TF0215/16



Features

- Efficient, low-cost solution for driving MOSFETs and IGBTs
- Wide supply voltage operating range: 4.5V to 18V
- 1.9A source / 1.8A sink output current capability
- Inverting and non-inverting input configurations
- Undervoltage lockout for V_{cc} supply.
- Fast propagation delays (35ns typical)
- Fast rise and fall times (15ns typical)
- Logic input (IN) 3.3V capability
- Space saving SOT23-5L package
- Extended temperature range: -40°C to +125°C

Applications

- Switch mode power supplies
- Motor Drive
- Line Drivers
- DC-DC Converters



Description

The TF0215/16 high speed, low side MOSFET and IGBT drivers are capable of driving 1.9A of peak current. The TF0215/16 logic inputs are compatible with standard TTL and CMOS levels (down to 3.3V) to interface easily with MCUs. Internal undervoltage lockout (UVLO) will protect MOSFET with loss of supply by turning off the output when V_{cc} falls below operating range. Fast and well matched propagation delays allow high speed operation, enabling a smaller, more compact power switching design using smaller associated components.

High Speed, Low-Side, Single Gate Driver

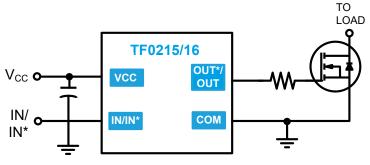
These devices are highly resistant to noise by being able to withstand up to 5V positive or negative on the ground pin without damage. Also they can accept 500mA of reverse current forced back into its outputs without damage or logic change. The TF0215 provides an inverted output and the TF0216 provides a noninverting output. The TF0215/16 comes in a space-saving SOT23-5L package and it operates over an extended -40 °C to +125 °C temperature range.

Ordering Information

Year Year Week Week

PART NUMBER	PACKAGE	PACK / Qty	MARK
TF0215-USQ	SOT-23-5L	T&R / 3,000	T0215/16
TF0216-USQ	SOT-23-5L	T&R / 3,000	YYWW

Typical Application



www.tfsemi.com Rev. 1.2

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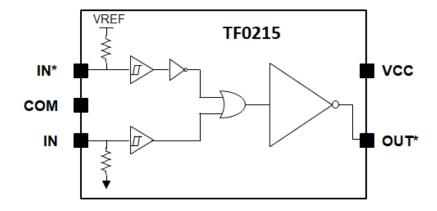
High Speed, Low-Side, Single Gate Driver

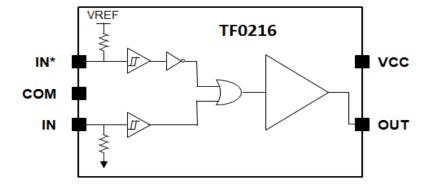


Pin Descriptions

PIN NAME	PIN NUMBER	PIN DESCRIPTION
IN*	1	Logic input, in phase with OUT* (TF0215), out of phase with OUT (TF0216), leave open when not in use.
СОМ	2	Supply return
IN	3	Logic input, out of phase with OUT* (TF0215), in phase with OUT (TF0216), leave open when not in use.
OUT*/OUT	4	Gate drive output
V _{cc}	5	Supply input

Functional Block Diagram







Absolute Maximum Ratings (NOTE1)

V _{cc} - Low-side fixed supply voltage	0.3V to +22V
V _{OUT} - Output voltage (OUT/OUT*)	
V _{IN} - Logic input voltage (IN)	
ESD Protection on all pins	2kV (HBM)
	400V (MM)

NOTE1 Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

P_D - Package power dissipation at $T_A \le 25$ °C	
SOT23-5L	TBD
SOT23-5L Thermal Resistance (NOTE2)	
$ heta_{JA}$	TBD °C/W
θ _{JC}	
T _J - Junction operating temperature	
T _L - Lead Temperature (soldering, 10 seconds)	+300°C
T _{stg} - Storage temerature	55 to 150 °C

NOTE2 When mounted on a standard JEDEC 2-layer FR-4 board.

Recommended Operating Conditions

Symbol	Parameter	MIN	MAX	Unit
V _{cc}	Supply voltage	4.5	18	V
V _{OUT}	Output voltage (OUT/OUT*)	0	V _{cc}	V
V _{IN}	Logic input voltage (IN)	0	5	V
T _A	Ambient temperature	-40	125	°C



Electrical Characteristics (NOTE3)

 $\rm V_{BIAS}$ (4.5V<V_{CC}<18V), ~T_A=25~^{\circ}C , unless otherwise specified.

Symbol	Parameter	Conditions	MIN	ТҮР	MAX	Unit	
DC Chara	DC Characteristics						
V _{IH}	Logic "1" input voltage		2.4	1.6			
V _{IL}	Logic "0" input voltage			1.3	0.8	V	
I _{IN+}	Logic "1" input bias current	$V_{IN} = 3V, V_{IN*} = 0V$			5		
I _{IN-}	Logic "0" input bias current	$V_{IN} = 0V, V_{IN*} = 3V$			2	μΑ	
V _{OH}	High level output voltage, V _{BIAS} - V _O			25			
V _{OL}	Low level output voltage			25		mV	
I _{ccQ}	V _{CC} quiescent supply current	V _{IN} = 0V or 3V		50	100	μА	
I _{O+}	Output high short circuit pulsed current	V _{CC} = 12V		1.9			
I _{O-}	Output low short circuit pulsed current	V _{CC} = 12V		1.8		A	
R _{OH}	Output Resistance, High	$I_{OUT} = 10 \text{mA}, V_{CC} = 12 \text{V}$		3.3		Ω	
R _{OL}	Output Resistance, Low	$I_{OUT} = 10 \text{mA}, V_{CC} = 12 \text{V}$		2.3		Ω	
Switchin	g Characteristics						
t _r	Turn-on rise time	C _L = 1000pF, V _{CC} = 12V		15	25	ns	
t _f	Turn-off fall time	$C_L = 1000 \text{pF}, V_{CC} = 12 \text{V}$		15	25	ns	
t _{on}	Turn-on propogation delay	V _{CC} = 12V		35	50	ns	
t _{off}	Turn-off propogation delay	V _{CC} = 12V		35	55	ns	

NOTE3 The V_{IN} and I_{IN} parameters are applicable to the logic input pin: IN. The V_{O} and I_{O} parameters are applicable to the output pins: OUT and OUT*

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Electrical Characteristics (over operating temperature range)

 $\rm V_{BIAS}$ (4.5V<V_{CC}<18V), ~40°C < T_{C}<125 °C , unless otherwise specified.

Symbol	Parameter	Conditions	MIN	ТҮР	мах	Unit
DC Chara	octeristics					'
V _{IH}	Logic "1" input voltage		2.4			
V _{IL}	Logic "0" input voltage				0.8	V
I _{IN+}	Logic "1" input bias current	V _{IN} = 3V			10	
I _{IN-}	Logic "0" input bias current	V _{IN} = 0V		0	5	μΑ
V _{OH}	High level output voltage, V _{BIAS} - V _O			25		
V _{OL}	Low level output voltage			25		mV
I _{ccq}	V _{cc} quiescent supply current	V _{IN} = 0V or 3V		0.1	0.2	mA
R _{OH}	Output Resistance, High	I _{OUT} = 10mA, V _{CC} = 12V			10	Ω
R _{OL}	Output Resistance, Low	I _{OUT} = 10mA, V _{CC} = 12V			7	Ω
Switchin	g Characteristics					
t _r	Turn-on rise time	C _L = 1000pF, V _{CC} = 12V		30	40	ns
t _f	Turn-off fall time	$C_L = 1000 pF, V_{CC} = 12 V$		30	40	ns
t _{on}	Turn-on propogation delay	V _{CC} = 12V		45	55	ns
t _{off}	Turn-off propogation delay	V _{CC} = 12V		50	60	ns

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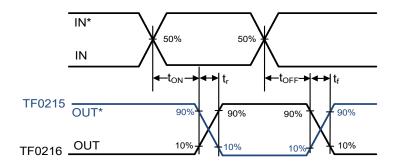


Figure 1. Switching Time Waveform Definitions

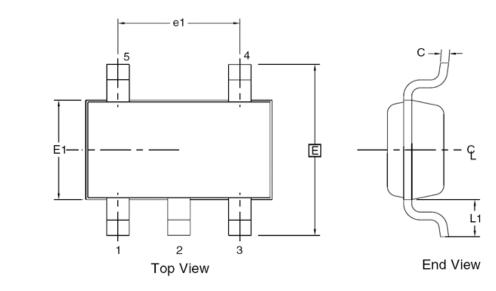
Input/Output response table

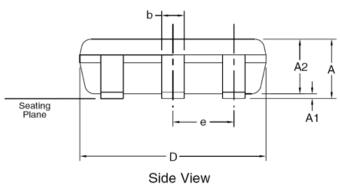
Input pin	Input logic	TF0215 (OUT*)	TF0216 (OUT)
IN	Н	L	Н
IN	L	Н	L
IN*	Н	Н	L
IN*	L	L	Н

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Package Dimensions (SOT23-5L)

Please contact support@tfsemi.com for package availability.





COMMON DIMENSIONS (Unit of Measure = mm)

SYMBOL	MIN	NOM	MAX	NOTE
А	-	-	1.10	
A1	0.00	_	0.10	
A2	0.70	0.90	1.00	
С	0.08	-	0.20	4
D	2.90 BSC			2, 3
E	2.80 BSC			2, 3
E1	1.60 BSC			2, 3
L1	0.60 REF			
е	0.95 BSC			
e1	1.90 BSC			
b	0.30	-	0.50	4, 5

Rev.	Change	Owner	Date
1.0	First release	Keith Spaulding	6/21/2017
1.1	Specs adjusted from pre production testing	Keith Spaulding	2/8/2018
1.2	Add Order Information	Duke Walton	12/15/2020

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